N-Channel 100-V (D-S) MOSFET

Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed
- Small Footprint DFN3x2-8L package

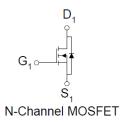
Typical Applications:

- Telecom DC/DC converters
- · White LED boost converters
- Industrial DC/DC conversion
- Automotive Entertainment and GPS DC/DC conversion

PRODUCT SUMMARY				
V _{DS} (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)		
100	280 @ V _{GS} = 10V	2.1		
100	355 @ V _{GS} = 4.5V	1.9		







ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)							
Parameter	Symbol	Limit	Units				
Drain-Source Voltage			100	V			
Gate-Source Voltage		V_{GS}	±20	٧			
Continuous Drain Current ^a	T _A =25°C	· I _D	2.1				
Continuous Drain Current	T _A =70°C		1.7	Α			
Pulsed Drain Current ^b		I _{DM}	±10				
Continuous Source Current (Diode Conduction) a		I _S	3	Α			
Power Dissipation ^a	T _A =25°C	P_{D}	2.5	W			
Fower Dissipation	T _A =70°C] 'D	1.6				
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55 to 150	°C			

THERMAL RESISTANCE RATINGS							
Parameter	Symbol	Maximum	Units				
Maximum Junction-to-Ambient ^a	t <= 10 sec	$R_{\theta JA}$	50	°C/W			
Maximum Junction-to-Ambient	Steady State	IΛθJA	90				

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Electrical Characteristics

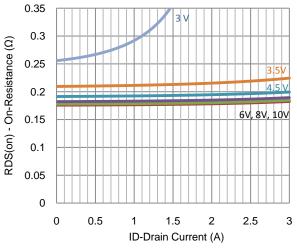
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \text{ uA}$	3.5	V			
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA	
Zara Cata Valtaria Dunin Current		$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}$	= 80 V, V _{GS} = 0 V		1	uA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			10	uA	
On-State Drain Current	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	10			Α	
Drain-Source On-Resistance	r	$V_{GS} = 10 \text{ V}, I_D = 1.7 \text{ A}$			280)	
Dialii-Source Oil-Resistance	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 1.5 \text{ A}$			355	mΩ	
Forward Transconductance	g _{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 1.7 \text{ A}$		5		S	
Diode Forward Voltage	V_{SD}	$I_{S} = 1.5 \text{ A}, V_{GS} = 0 \text{ V}$		0.8		V	
		Dynamic					
Total Gate Charge	Q_g			4.1			
Gate-Source Charge	Q_gs	$V_{DS} = 50 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 1.7 \text{ A}$		1		nC	
Gate-Drain Charge	Q_gd			1.9]	
Turn-On Delay Time	t _{d(on)}			3			
Rise Time	t _r	$V_{DD} = 50 \text{ V}, R_L = 30 \Omega, I_D = 1.7 \text{ A},$		3		no	
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = 10 \text{ V}, R_{GEN} = 6 \Omega$		10		ns	
Fall Time	t _f			3			
Input Capacitance	C _{iss}			420			
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		50		pF	
Reverse Transfer Capacitance	C _{rss}			30			

Notes

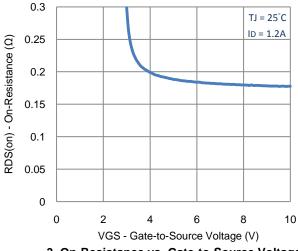
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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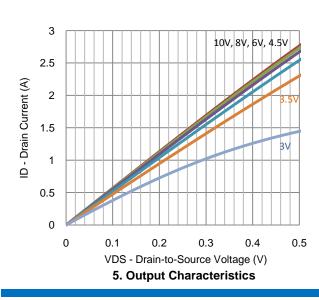
Typical Electrical Characteristics

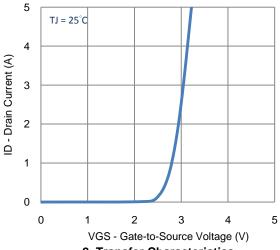


1. On-Resistance vs. Drain Current

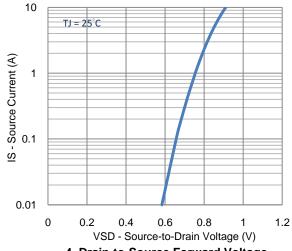


3. On-Resistance vs. Gate-to-Source Voltage

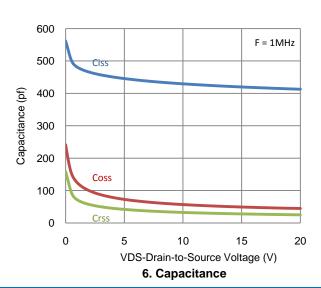




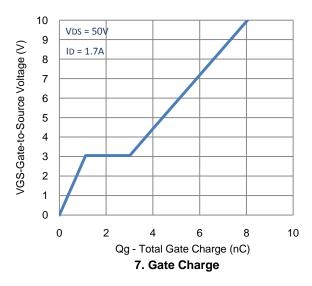
2. Transfer Characteristics

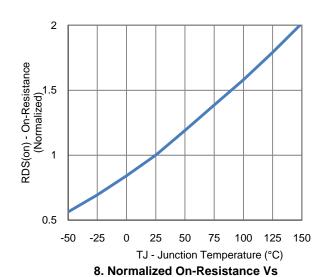


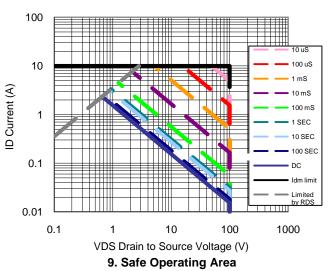
4. Drain-to-Source Forward Voltage

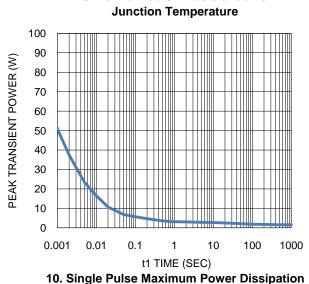


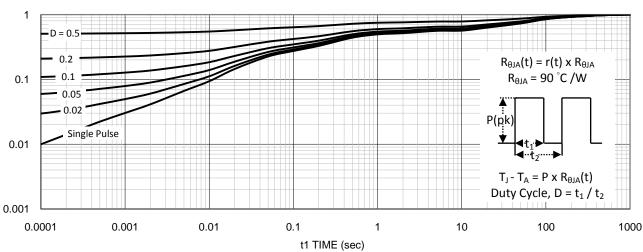
Typical Electrical Characteristics





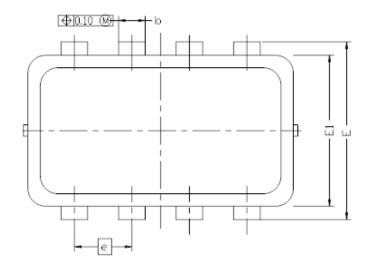


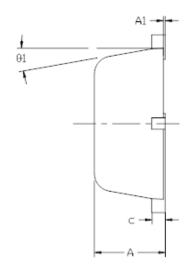


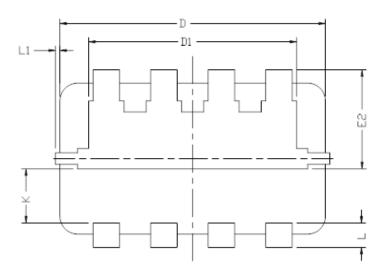


11. Normalized Thermal Transient Junction to Ambient

Package Information







MILLIMETERS INCHES							
DIM.				21.101.100			
	MIN	NDM	MAX	MIN	NDM	MAX	
Α	0.700	0.80	0.900	0.0276	0.0315	0.0354	
A1	0.00		0.05	0.000		0.002	
b	0.24	0.30	0.35	0.009	0.012	0.014	
	0.08	0.152	0.25	0.003	0.006	0.010	
D	3.00 BSC			0.118 BSC			
D1	2.30	2.35	2.40	0.091	0.093	0.095	
E	2.00 BSC			0.079 BSC			
E1	1	1.70 BSC			0.067 BSC		
E2	1.065	1.115	1.165	0.042	0.044	0.046	
6	0.65 BSC			0.026 BSC			
L	0.20	0.275	0.400	0.008	0.011	0.0157	
K	0.56	0.61	0.66	0.022	0.024	0.026	
L1	0		0.100	0		0.004	
91	0	10	12	0	10	12	

Note:

- 1. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
- 2. Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Tie Bar Burrs, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.